EPITAXIAL HETEROSTRUCTURE OF A CUPRATE SUPERCONDUCTOR AND PRASEODYMIUM NICKELATE

Petrzhik A.M.^{1*}, Shadrin A.V.^{1,2}, Kislinskii Yu.V.¹, Constantinian K.Y.¹, Ovsyannikov G.A.¹, Christiani G.³, Logvenov G.³

¹ Kotel'nikov IRE RAS, Moscow, Russia, <u>*petrzhik@hitech.cplire.ru</u>
² MIPT, Dolgoprudny, Moscow Region, Russia
³ Max Planck Institute for Solid State Research, Stuttgart, Germany

Heterostructures with epitaxial interfaces of transition metal oxides with superconducting properties and materials with strain-controlled characteristics, in particular with nickelates, attract an increased interest due to opportunities for development of electronic devices with spin polarized electron transport [1]. As far, we report on the first experimental data on the XRD and resistive characteristics of epitaxial YBa₂Cu₃O_{7-x}/PrNiO₃/YBa₂Cu₃O_{7-x} heterostructure with the 6 nm thick praseodymium nickelate, PrNiO₃, interlayer. Five structures were fabricated on one substrate with square geometry and widths 10 ... 50 mm. With decreasing temperature, the voltage dependence of the conductivity, G(V), shows deviation from the symmetric one, becoming noticeable already at T = 77 K, the temperature lower than the critical temperature of cuprate superconductor YBa₂Cu₃O_{7-x}. This hints on appearance of spin-polarized electron transport in heterostructure. 1. S. Catalano, et al., Rep. Prog. Phys. **81**, 046501(2018)

Heterostructure on NdGaO₃ substrate

Conductance for 40x40 µm² sample



XRD Ø/20 symmetric scan



I-V evolution with temperature

Conclusions

The YBa₂Cu₃O_{7-x}/PrNiO₃/YBa₂Cu₃O_{7-x} heterostructures were fabricates and characterized by XRD, and voltage dependencies of conductance at temperatures T=300, 77, and 4.2 K. An asymmetry in G(V) functions has been registered: at T=77 K the ration g=G(-330 mV)/G(+330 mV) was 32%, at T=4.2 K g=40 %. However, further studies are needed in order to reveal the impact of praseodymium nickelate barrier at reduced temperatures.